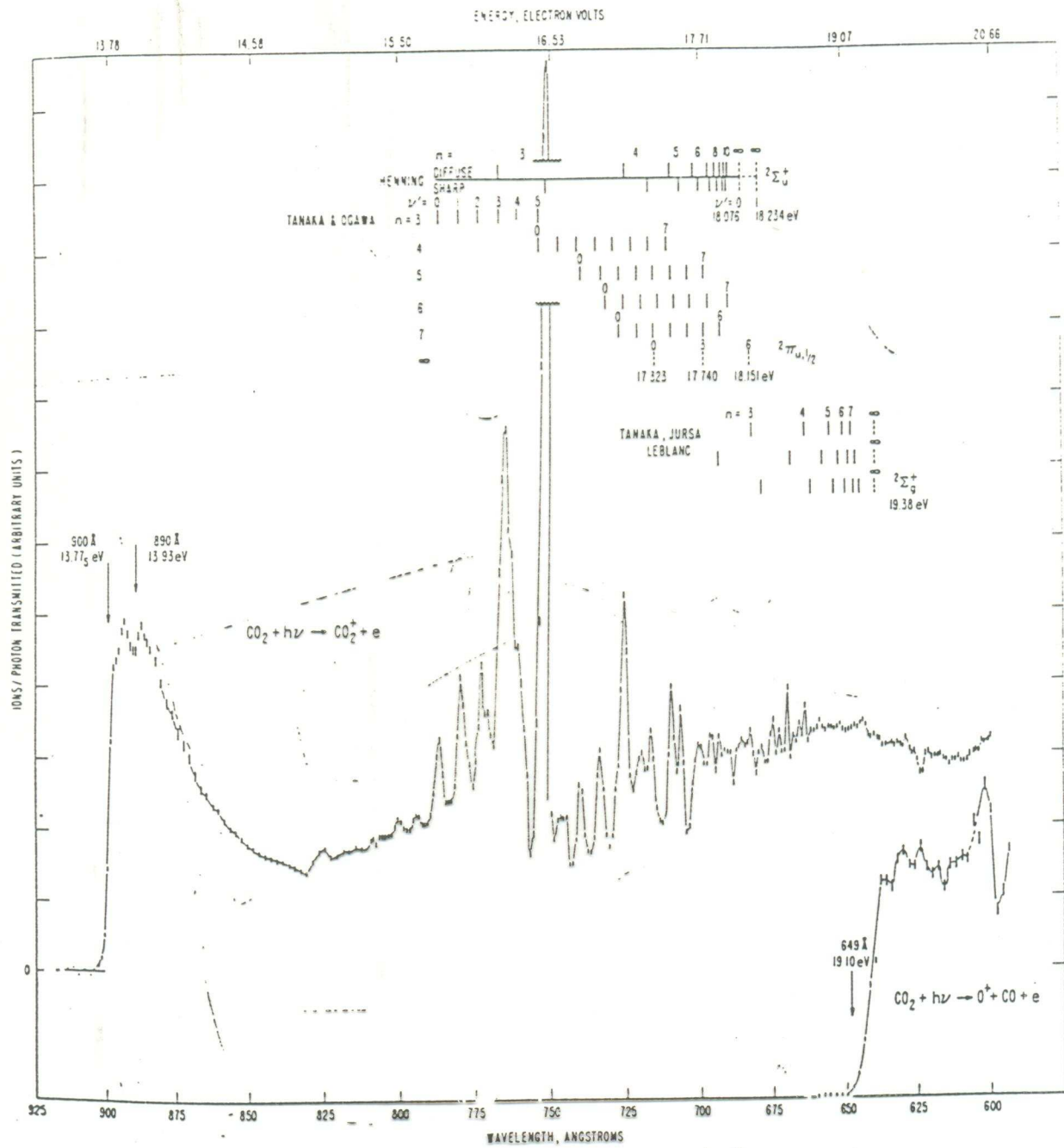
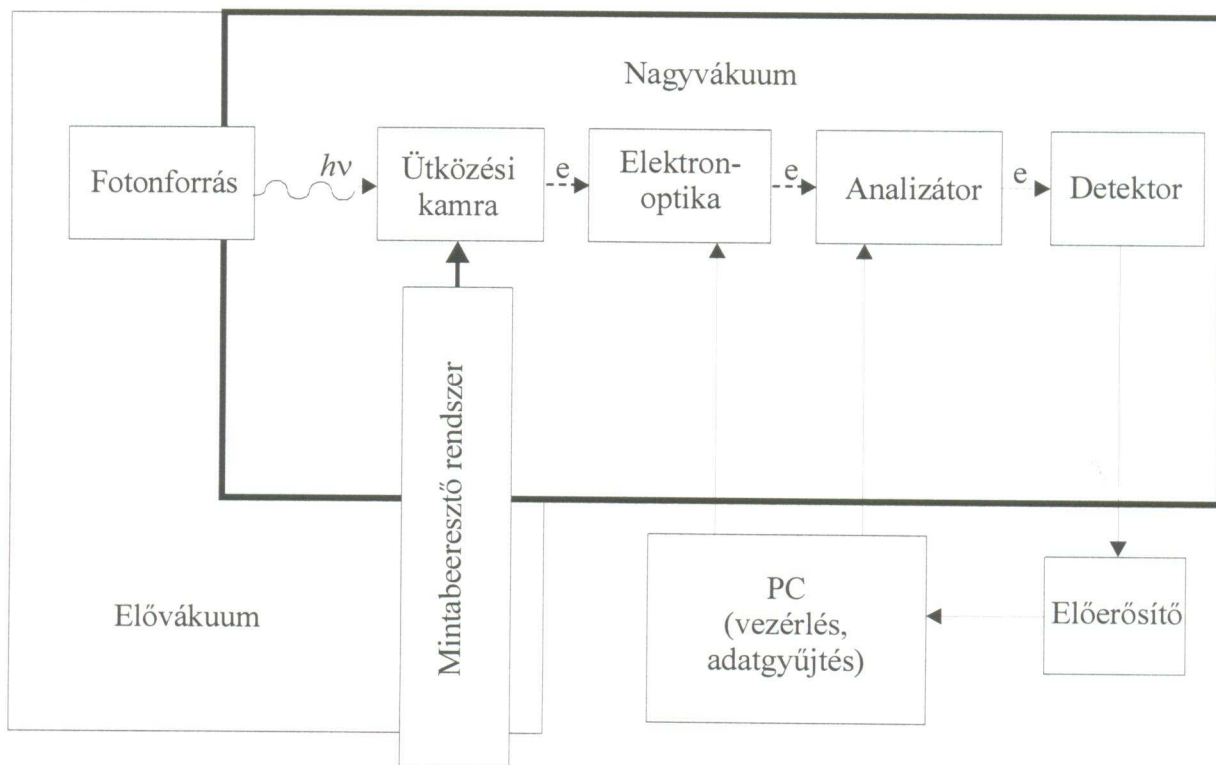


2. Vacuum monochromator and mass spectrometer. A, electron multiplier ion detector; B, photomultiplier radiation ion beam; D, G, I, O, to pumping systems; E, ion chamber; F, permanent magnet; H, monochromator exit slit; J, light monochromator entrance slit; L, grating turntable; M, grating; N, Seya type vacuum monochromator (Weissler et al. [2

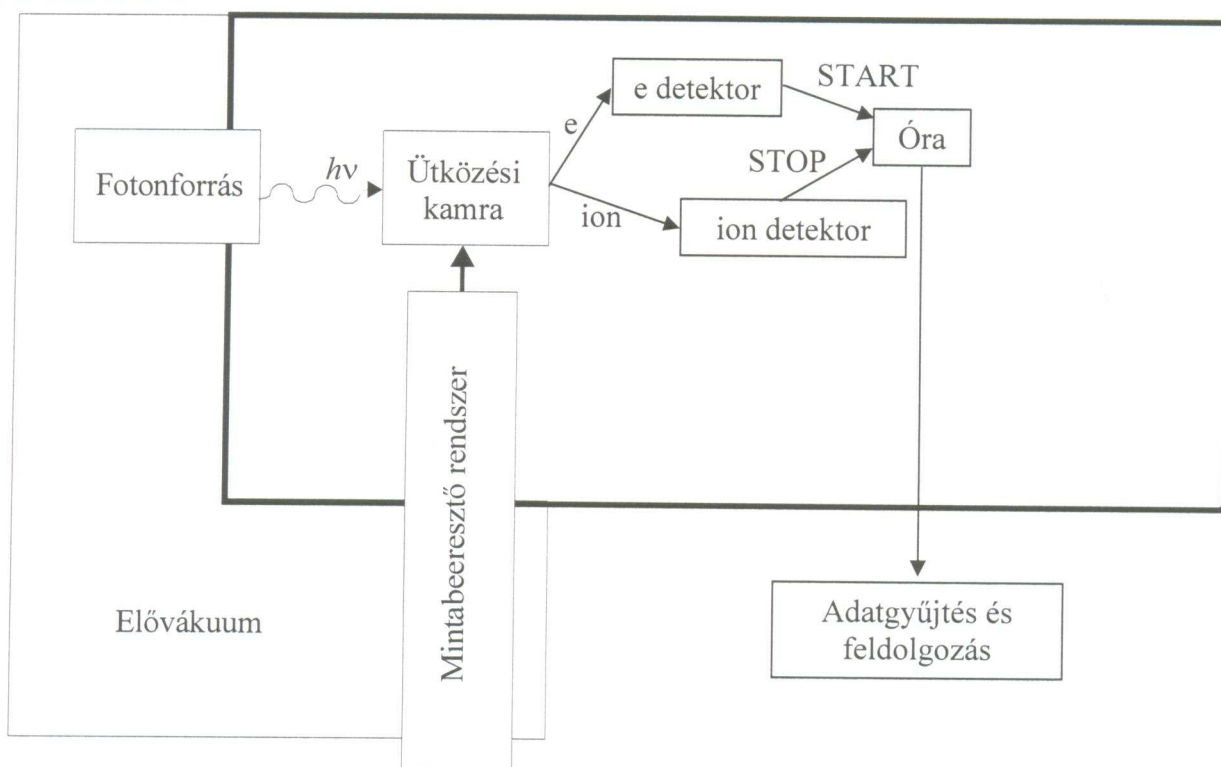


18. Photoionization-efficiency curves for the CO_2^+ and O^+ ions of carbon dioxide. The ordinate scale for the molecule ion is 20 times that of the atom ion (Dibeler and Walker [111]).

UPS



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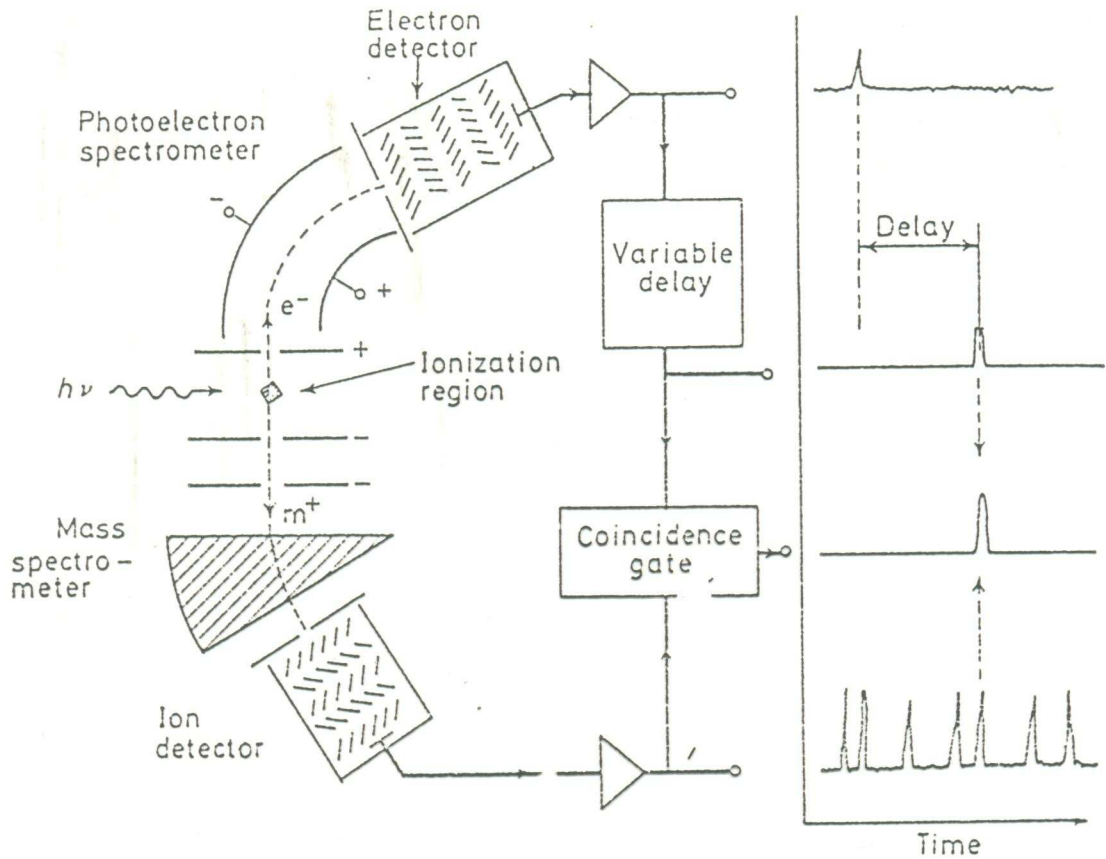


Figure 7.5. Simplified scheme of a photoelectron-photoion coincidence spectrometer. The peaks in the idealized wave-forms on the right indicate detection of single electrons and single ions; there are generally many more ions than electrons because the collection efficiency of mass spectrometers is higher than that of photoelectron spectrometers

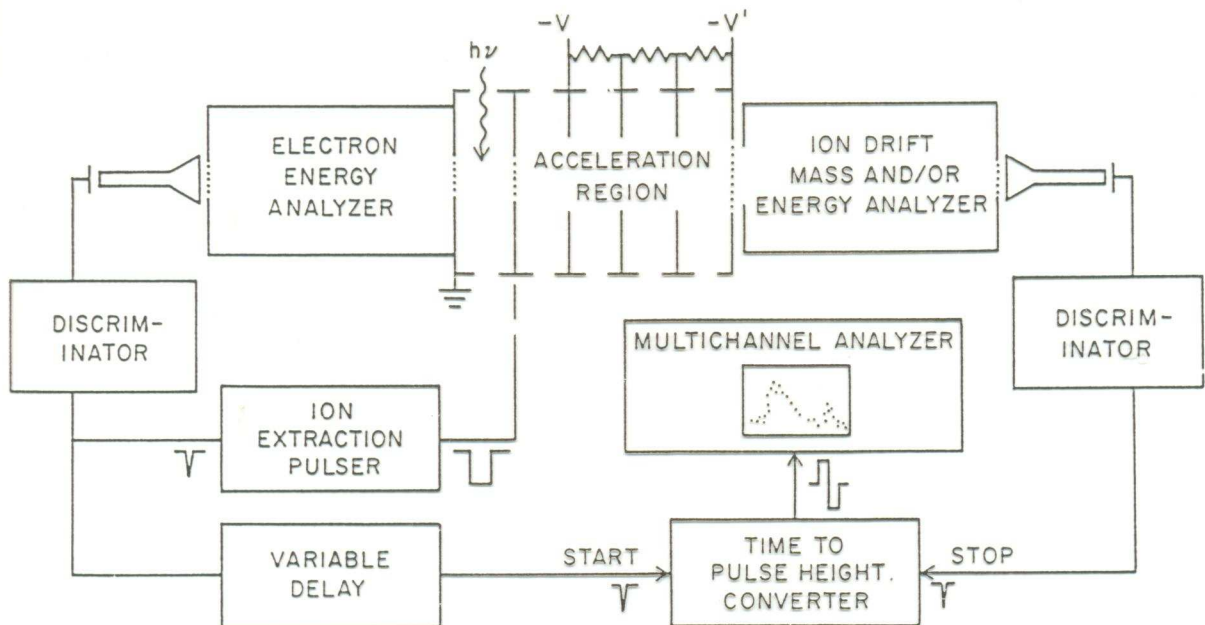
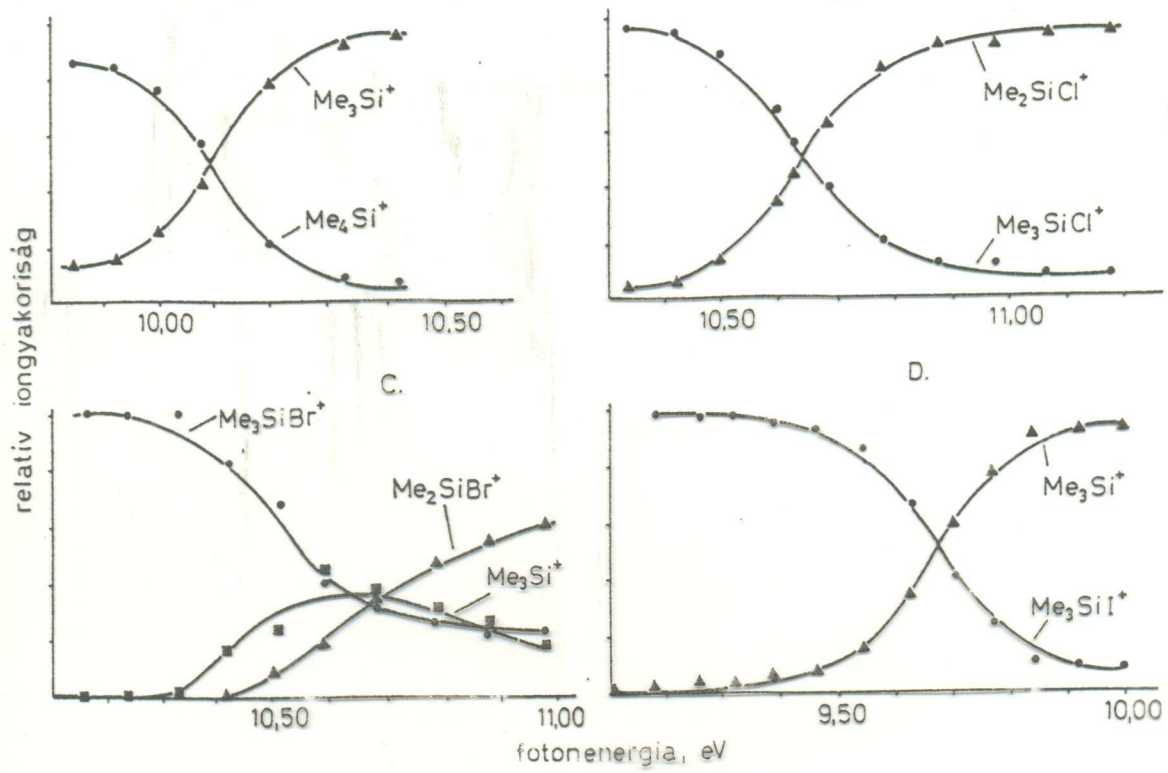
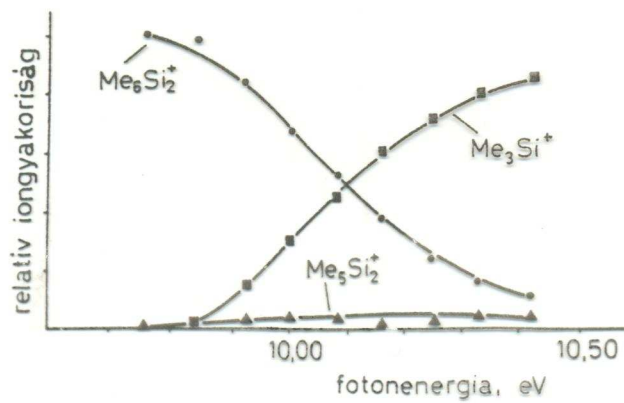


FIG. 1 Block diagram of a photoion-photoelectron coincidence experiment.



2. ábra

A tetrametil-, trimetil-klór-, trimetil-bróm- és trimetil-jód-szilán letörési diagramja



1. ábra

A hexametil-diszilán letörési diagramja

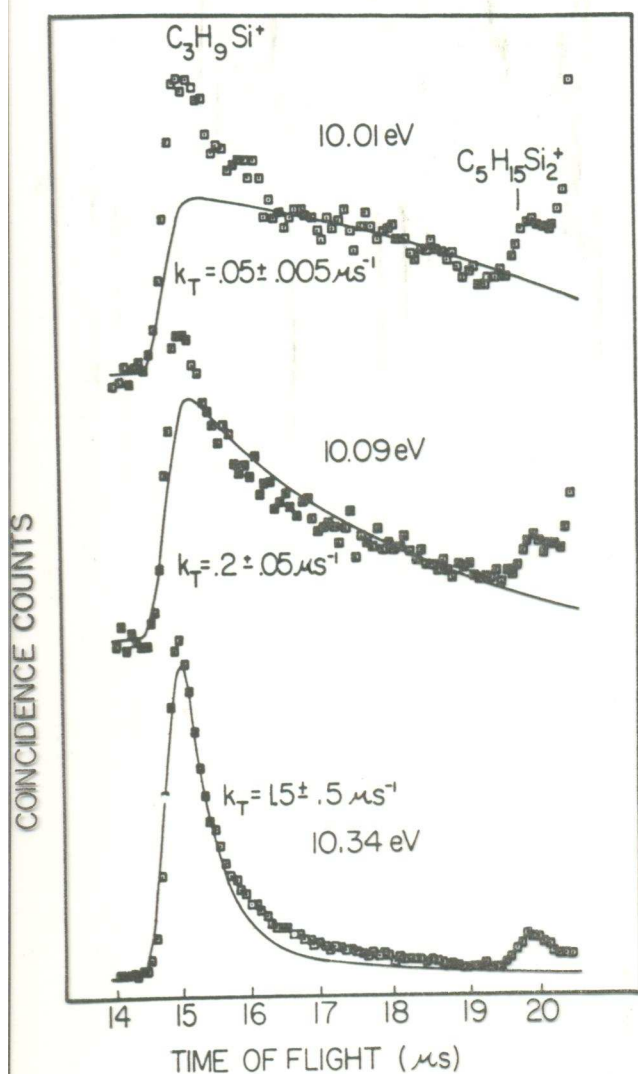


Figure 3. Time-of-flight (TOF) spectra for Me_3Si^+ (m/z 73) and Me_5Si_2^+ (m/z 131) at three different photon energies in the metastable region.

distributions in coincidence with zero kinetic energy electrons, over a range of ion internal energies ranging from 9.9 to 11.0 eV. Some of the experimental results are shown in Figure 3, in which the points are the experimental data while the solid curves are calculated TOF distributions based on a single unimolecular decay. The experimental TOF distributions at the lower energies clearly exhibit a sharp peak on top of the very asymmetric Me_3Si^+ peak. This peak is usually extremely weak but shows up at low photon energies at which the slow HMDS⁺ dissociation produces a very weak m/z 73 peak. For the reasons outlined below, this sharp peak is attributed to an impurity. A mass spectrum at 9.6 eV, well below the energy at which the m/z 73 peak is apparent, showed two peaks at m/z 72 and 104. The higher mass peak was eliminated by purification by GLC. However, this procedure did not reduce the amount of the m/z 72 component. Because this peak is asymmetric, it can only come from a molecular ion (i.e., impurity), or from a rapid dissociation of the HMDS parent ion. The latter would imply a nonstatistical dissociation, an explanation which is not likely and is not supported by any other findings of this study. We therefore conclude that it arises from an impurity, which is present in minute amounts. Nevertheless, it is evident from the result of the long counting times required near the HMDS⁺ dissociation threshold.

The experimentally determined rates in Figure 3 are total rates

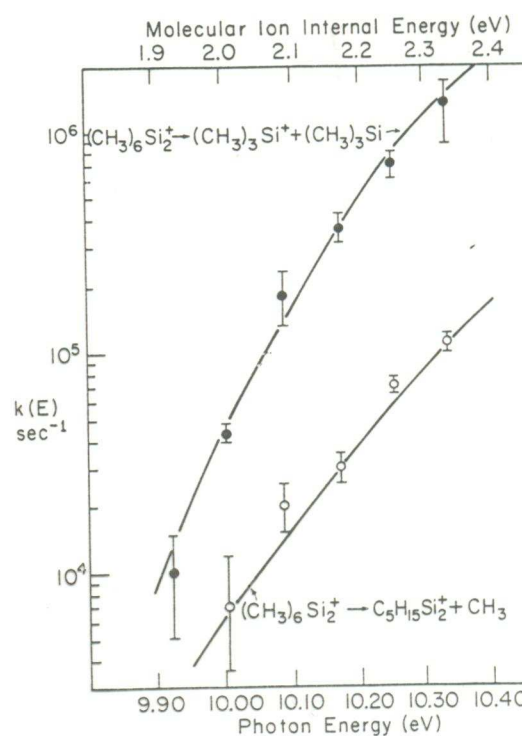


Figure 4. The decay rate, $k(E)$, as a function of energy for the dissociation of hexamethyldisilane⁺ to Me_3Si^+ + $\text{Me}_3\text{Si}\cdot$ and Me_5Si_2^+ to Me_3Si^+ + $\text{Me}_3\text{Si}\cdot$. The solid curves are the results of RRKM/QET calculations using the vibrational frequencies of Table III and activation energies of 0.26 eV respectively for the production of m/z 73 and 131. The ion internal energy is related to the photon energy by $E_{\text{int}} = h\nu - I_{\text{HMD}} - E_{\text{th}}$, where I_{HMD} (ionization energy) minus the HMDS internal thermal energy at 300 K is 0.260 eV.

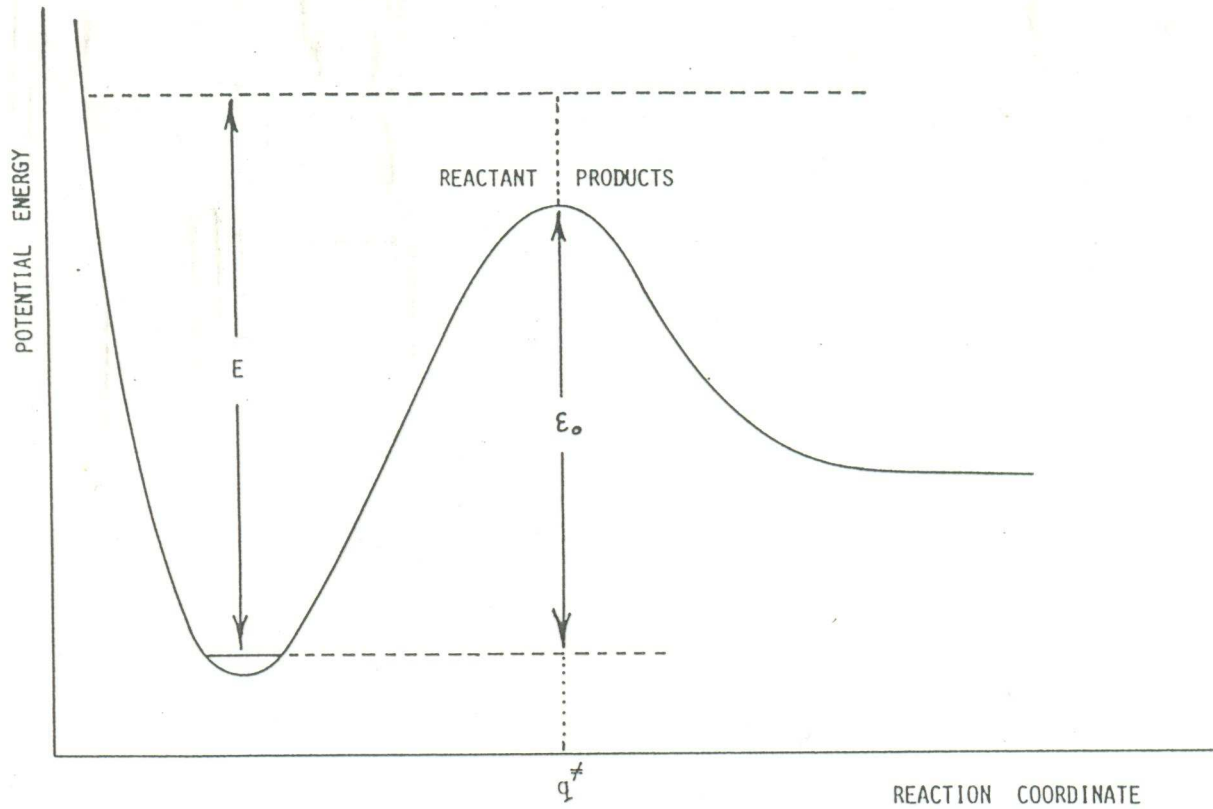
When different products originate from the same parent ion, the total decay rates can be converted into rates of formation of the individual fragments by using the ratios of the relative areas as ratios of rates to various fragments. This procedure has been discussed and applied previously.^{18,28} The results are shown in Figure 4 where the points are the experimentally determined rate constants at different photon energies. The $k(E)$ for the formation of Me_3Si^+ rises more rapidly with a rise in energy than that of the Me_5Si_2^+ ion. In terms of RRKM/QET, this suggests a tighter activated state for Me_5Si_2^+ formation. On this basis, by extrapolating to lower energies one can expect a lower $k(E)$ resulting in a lower thermochemical threshold for the formation of Me_3Si^+ .

According to the statistical theory^{29,30} (RRKM), the unimolecular decay rate is given by

$$k(E) = \sigma \frac{\int_{\epsilon=0}^{E-E_0} \rho^{\ddagger}(E) d\epsilon}{h\rho(E)}$$

where E_0 is the minimum energy needed for reaction, $\rho^{\ddagger}(E)$ and $\rho(E)$ are the densities of internal energy for the transition state and precursor ions, respectively, and σ is a statistical factor representing the number of independent ways the transition state can be formed. For $k(E)$ to be calculated, E_0 and vibrational frequencies for the transition state and molecular ion must be assumed. In unimolecular reactions the vibrational frequencies for the molecular ion are assumed to be those of the neutral molecule.^{31,32} By using the above combinations of the other two parameters, best fits to the data lines in Figure 4 were found. The best transition-state energies and vibrational frequencies for production of m/z 73 and 131 ions together with the vibrational frequencies for the ion normal vibrations are listed in Table III. In order to compare the transition state with the molecular ion, the

RRKM/QET



$$k(E) = \sigma \frac{\int_{\epsilon=0}^{E-E_0} \rho^\ddagger(E) d\epsilon}{h\rho(E)}$$

$$k(E) = \frac{\prod_i^s \nu_i}{\prod_{i \neq z}^{s-1} \nu_i} \left(\frac{E - \epsilon_0}{E} \right)^{s-1}$$

$$k(E) = \frac{\prod_i^s \nu_i}{\prod_{i \neq z}^{s-1} \nu_i} \left(\frac{E - \epsilon_0 + E_z^\ddagger}{E + E_z} \right)^{s-1}$$